NSN 5961-01-318-5164

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Inclosure Material:

Metal

Overall Length:

23.11 millimeters

Overall Height:

5.84 millimeters

Overall Width:

10.03 millimeters

Internal Configuration:

Junction contact

Mounting Method:

Press fit

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

65.0 breakdown voltage, collector-to-base, emitter open and 65.0 breakdown voltage, collector-to-emitter, base open and 3.5 breakdown voltage, emitter-to-base, collector open

Current Rating Per Characteristic:

22.00 amperes source cutoff current

Power Rating Per Characteristic:

875.0 watts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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